NSN 5962-01-038-0783

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AeroBase Group

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Body Length:	
0.896 inches	
Body Width:	
Between 0.220 inches and 0.310 inches	
Body Height:	
Between 0.140 inches and 0.185 inches	
Maximum Power Dissipation Rating:	
625.0 milliwatts	
Operating Tempurature Range:	
+0.0/+70.0 degrees celsius	
Storage Tempurature Range:	
-65.0/+150.0 degrees celsius	
End Application:	
Receiving set, special purpose type an/fsq-9 (v)	
Features Provided:	
Hermetically sealed and monolithic and positive outputs and w/enable and programmable and programmed and w/buffered output and	
w/decoded output and w/storage	
Inclosure Material:	
Ceramic and glass	
Inclosure Configuration:	
Dual-in-line	
Output Logic Form:	
Transistor-transistor logic	
Input Circuit Pattern:	
10 input	
Case Outline Source And Designator:	
D-2 mil-m-38510	
Terminal Surface Treatment:	
Solder	
Voltage Rating And Type Per Characteristic:	
5.5 volts power source	
Time Rating Per Chacteristic:	
50.00 nanoseconds propagation delay time, low to high level output	
Memory Device Type:	
Rom	
Test Data Document:	
28480-a-1816-9003-1 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer draw	/ing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)	
Terminal Type And Quantity:	
16 printed circuit	
Shelf Life:	
N/a	
Unit Of Measure:	

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Demilitarization:

Yes - demil/mli

Fiig:

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